

**PRELIMINARY**

Rev. A2

LED450-01

- Blue LED
- 450 nm, 24 mW
- Chip: InGaN, 350 x 350 µm, 1 pc.
- 5 mm Clear Molding, Epoxy Resin
- Viewing Angle: 16°



Description

LED450-01 contains one InGaN LED chip die with a typical peak wavelength of **450 nm** and radiation power of **24 mW**. It comes in Ø5 mm clear molding package with soldered lead frame (lead free) and lens molded with epoxy resin.

Maximum Ratings ($T_{CASE}=25^\circ\text{C}$)

Parameter	Symbol	Min.	Values	Max.	Unit
Power Dissipation	P_D			200	mW
Forward Current	I_F			50	mA
Pulse Forward Current *1	I_{FP}			100	mA
Reverse Voltage	V_F			5	V
Thermal Resistance	R_{THJA}			220	K/W
Junction Temperature	T_J			120	°C
Operating Temperature	T_{CASE}	- 40		+ 100	°C
Storage Temperature	T_{STG}	- 40		+ 100	°C
Lead Solder Temperature *2	T_{SLD}			+ 265	°C

*1 duty=1%, pulse width = 10 µs

*2 must be completed within 5 seconds

Electro-Optical Characteristics ($T_{CASE}=25^\circ\text{C}$)

Parameter	Symbol	Conditions	Min.	Values	Typ.	Max.	Unit
Peak Wavelength	λ_P	$I_F=20\text{mA}$	440			460	nm
Dominant Wavelength	λ_D	$I_F=20\text{mA}$		455			nm
Half Width	$\Delta\lambda$	$I_F=20\text{mA}$		19			nm
Forward Voltage	V_F	$I_F=20\text{mA}$		3.0		4.0	V
	V_{FP}	$I_{FP}=100\text{mA}$		3.7			
Radiated Power *1	P_0	$I_F=20\text{mA}$ $I_{FP}=100\text{mA}$	16	24			mW
				92			
Radiant Intensity *2	I_E	$I_F=20\text{mA}$ $I_{FP}=100\text{mA}$		200			mW/sr
				770			
Luminous Flux	Φ_V	$I_F=20\text{mA}$		850			mlm
Viewing Angle	$2\theta_{1/2}$	$I_F=20\text{mA}$		16			deg.
Rise Time	t_r	$I_F=20\text{mA}$		30			ns
Fall Time	t_f	$I_F=20\text{mA}$		30			ns

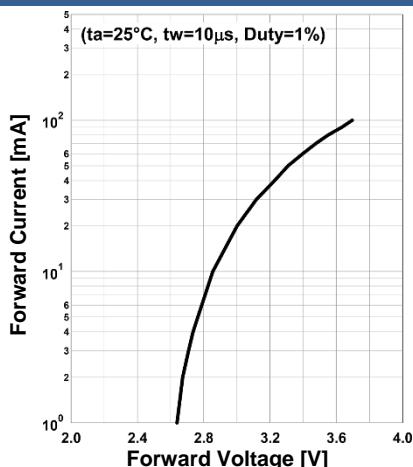
*1 measured by S3584-08

*2 measured by CIE127-2007 Condition B

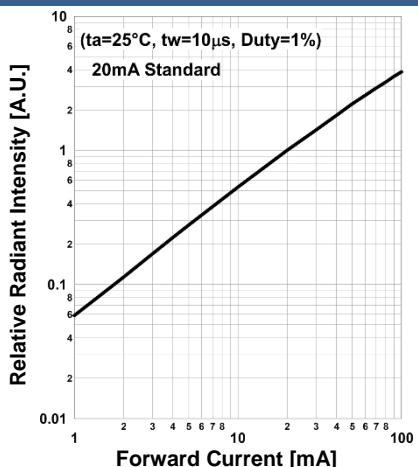


Typical Performance Curves

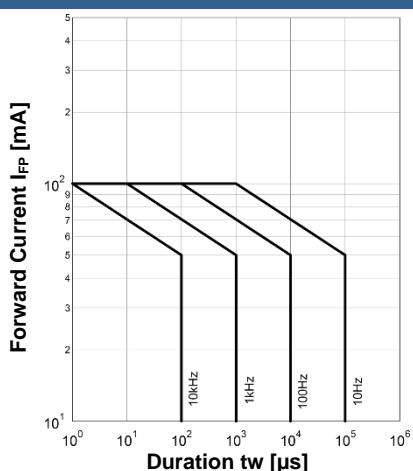
Forward Current vs. Forward Voltage



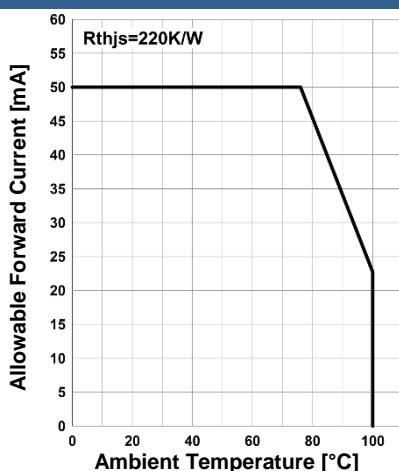
Rel. Radiant Intensity vs. Forward Current



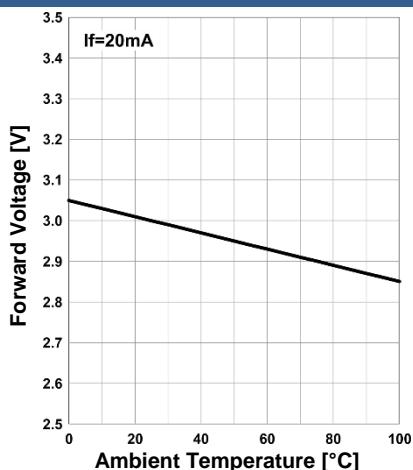
Forward Current vs. Pulse Duration



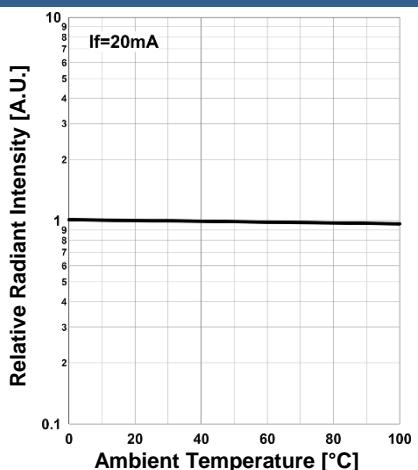
Allowed Forward Current vs. Ambient Temperature

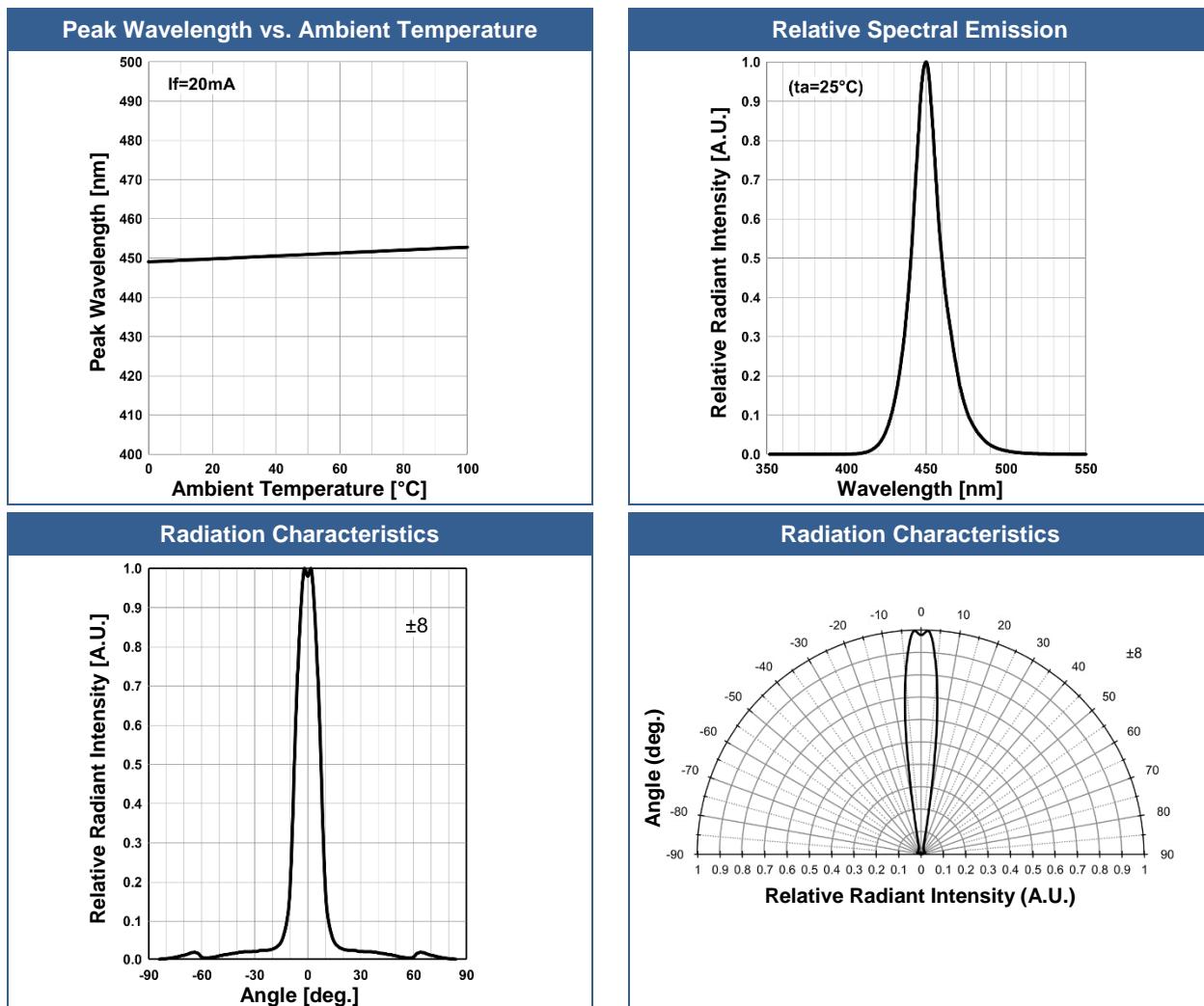


Forward Voltage vs. Ambient Temperature

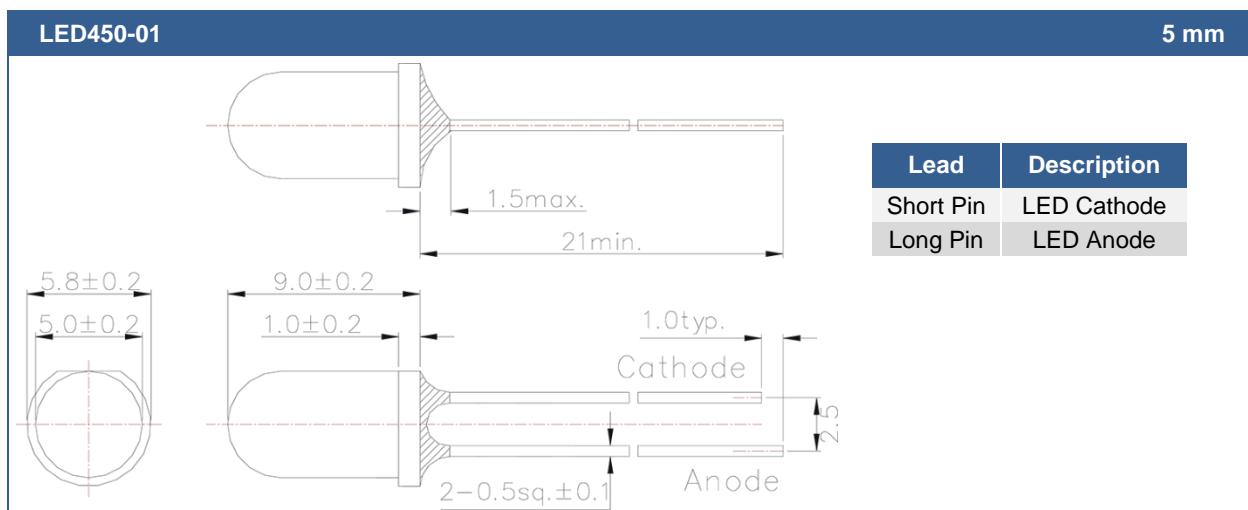


Rel. Radiant Intensity vs. Ambient Temperature





Outline Dimensions



All Dimensions in mm

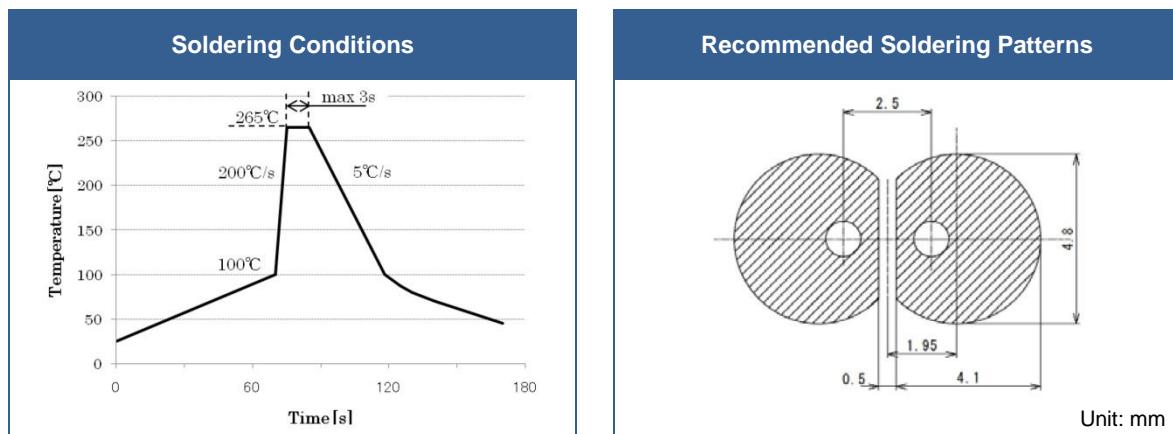


Precautions

Soldering:

- Do avoid overheating of the LED
- Do avoid electrostatic discharge (ESD)
- Do avoid mechanical stress, shock, and vibration
- Do only use non-corrosive flux
- Do not apply current to the LED until it has cooled down to room temperature after soldering

Recommended soldering conditions:



Above table specifies the maximum allowed duration and temperature during soldering. It is strongly advised to perform soldering at the shortest time and lowest temperature possible.

Cleaning:

Cleaning with isopropyl alcohol, propanol, or ethyl alcohol is recommended

DO NOT USE acetone, chloroform, trichloroethylene, or MKS

DO NOT USE ultrasonic cleaners

Static Electricity:

LEDs are sensitive to electrostatic discharge (ESD). Precautions against ESD must be taken when handling or operating these LEDs. Surge voltage or electrostatic discharge can result in complete failure of the device.

Radiation:

During operation these LEDs do emit light, which could be hazardous to skin and eyes, and may cause cancer. Do avoid exposure to the emitted light. Protective glasses if needed. It is further advised to attach a warning label on products/systems.

Operation:

Do only operate LEDs with a current source.

Running these LEDs from a voltage source will result in complete failure of the device.

Current of a LED is an exponential function of the voltage across it. Usage of current regulated drive circuits is mandatory.



Revisions History

Rel.	Rel. Date	Chapter	Modification	Page
A2	2020-08-24	Maximum Ratings	Included: Thermal Resistance, Junction Temperature T_{CASE} : -40..+100 °C (previously -30..+85 °C)	1
		Electro-Optical Characteristics	$\Delta\lambda$: typ. 19 nm (previously typ. 20 nm) V_F : typ. 3.0 V (previously max. 3.4 V) $2\theta_{1/2}$: 16° (previously 20°) P_o : min. 16 mW / typ. 24 mW (previously min. -- mW / typ. 20 mW) t_r : typ. 30 ns (previously typ. 1000 ns) t_f : typ. 40 ns (previously typ. 400 ns) Included: λ_D , I_E , ΦV , T_R , T_F , V_{FP} , P_o @ I_{FP} , I_E @ I_{FP}	1
		Typical Performance Curves	included	2-3
A1	2010-05-14	-	Initial release	-

© All Rights Reserved

The above specifications are for reference purpose only and subjected to change without prior notice